

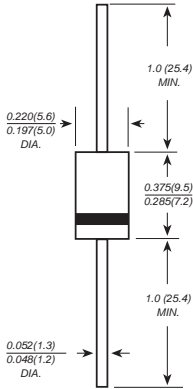


HER501 THRU HER508

HIGH EFFICIENCY RECTIFIERS

Reverse Voltage - 50 to 1000 Volts Forward Current -5.0 Amperes

DO-201AD



Dimensions in inches and (millimeters)

FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ High speed switching for high efficiency
- ◆ Low reverse leakage
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:
250°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: DO-201AD molded plastic body

Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.04 ounce, 1.10 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	HER 501	HER 502	HER 503	HER 504	HER 505	HER 506	HER 507	HER 508	UNITS	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	300	400	600	800	1000	VOLTS	
Maximum RMS voltage	V_{RMS}	35	70	140	210	280	420	560	700	VOLTS	
Maximum DC blocking voltage	V_{DC}	50	100	200	300	400	600	800	1000	VOLTS	
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A=50^\circ\text{C}$	$I_{(AV)}$	5.0								Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	200.0								Amps	
Maximum instantaneous forward voltage at 5.0A	V_F	1.0		1.3		1.70				Volts	
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	10.0 200.0								μA	
Maximum reverse recovery time (NOTE 1)	t_{rr}	50					70				ns
Typical junction capacitance (NOTE 2)	C_J	100.0					65.0				pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	10.0								$^\circ\text{C/W}$	
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +150								$^\circ\text{C}$	

Note: 1.Reverse recovery condition $I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$

2.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

3.Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

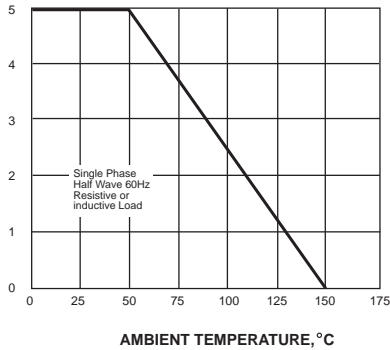


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RATINGS AND CHARACTERISTIC CURVES HER501 THRU HER508

AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT,
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

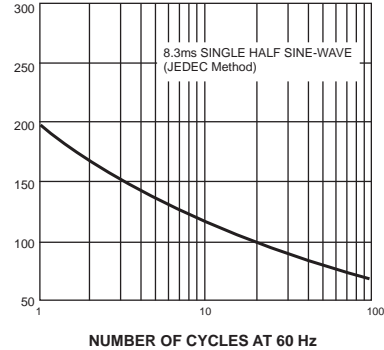
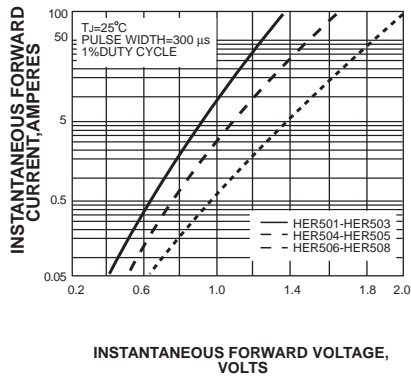


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS REVERSE CURRENT,
MICROAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS

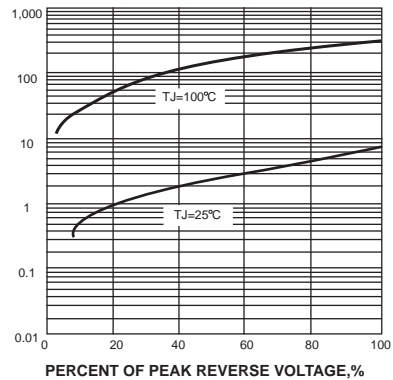
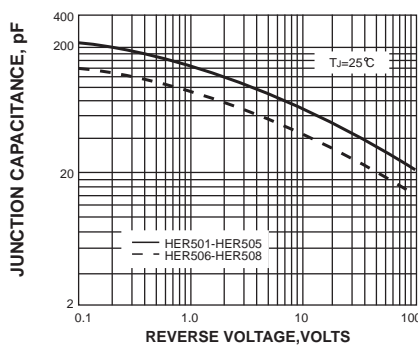
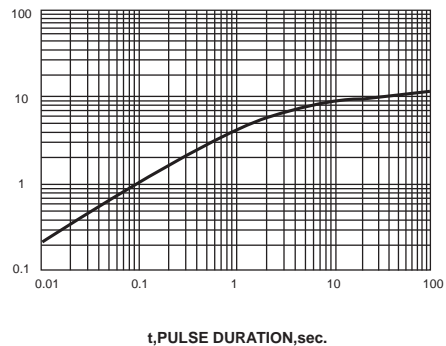


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!



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